

TOSHIBA THYRISTOR SILICON PLANAR TYPE

SF10G41A, SF10J41A

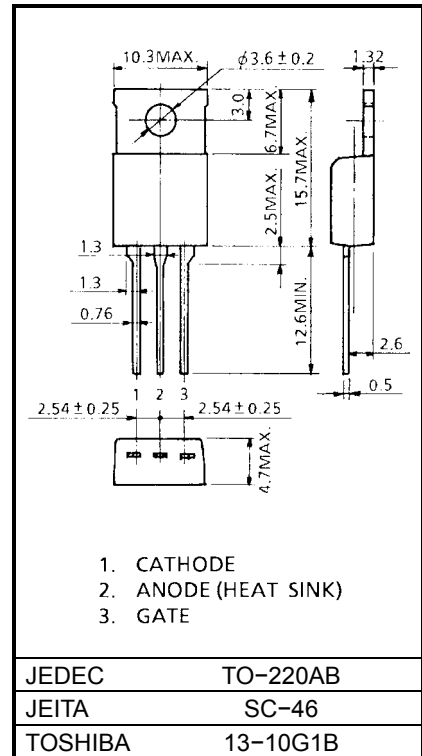
MEDIUM POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : $V_{DRM} = 400, 600V$
 Repetitive Peak Reverse Voltage : $V_{RRM} = 400, 600V$
- Average On-State Current : $I_T (AV) = 10A$
- Gate Trigger Current : $I_{GT} = 15mA (Max.)$

MAXIMUM RATINGS

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|---|-------------|------------|-------------|
| Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage | SF10G41A | 400 | V |
| | SF10J41A | 600 | |
| Non-Repetitive Peak Reverse Voltage (Non-Repetitive < 5ms, $T_j = 0 \sim 125^\circ C$) | SF10G41A | 500 | V |
| | SF10J41A | 720 | |
| Average On-State Current (Half Sine Waveform $T_c = 79^\circ C$) | $I_T (AV)$ | 10 | A |
| R.M.S On-State Current | $I_T (RMS)$ | 16 | A |
| Peak One Cycle Surge On-State Current (Non-Repetitive) | I_{TSM} | 160 (50Hz) | A |
| | | 176 (60Hz) | |
| I^2t Limit Value | I^2t | 125 | A^2s |
| Critical Rate of Rise of On-State Current | di / dt | 100 | $A / \mu s$ |
| Peak Gate Power Dissipation | P_{GM} | 5 | W |
| Average Gate Power Dissipation | $P_G (AV)$ | 0.5 | W |
| Peak Forward Gate Voltage | V_{FGM} | 10 | V |
| Peak Reverse Gate Voltage | V_{RGM} | -5 | V |
| Peak Forward Gate Current | I_{GM} | 2 | A |
| Junction Temperature | T_j | -40~125 | $^\circ C$ |
| Storage Temperature Range | T_{stg} | -40~125 | $^\circ C$ |

Unit: mm

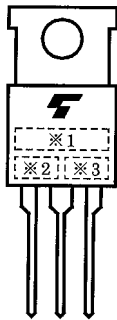


Weight: 2g

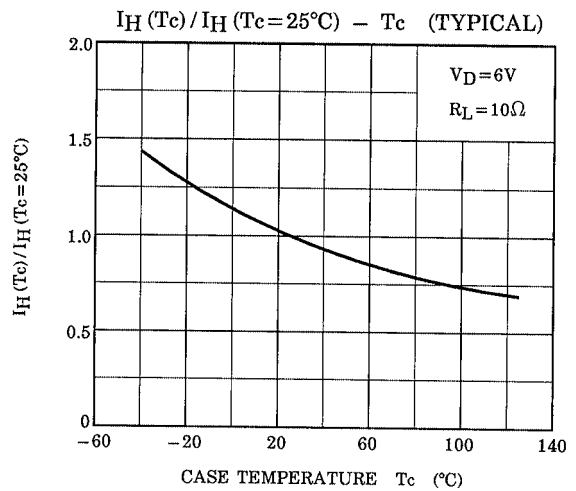
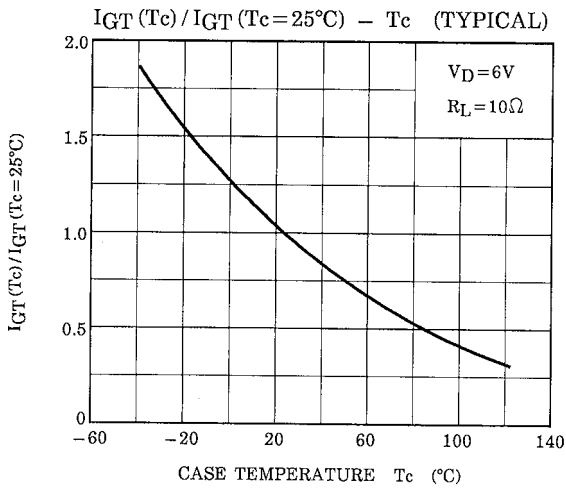
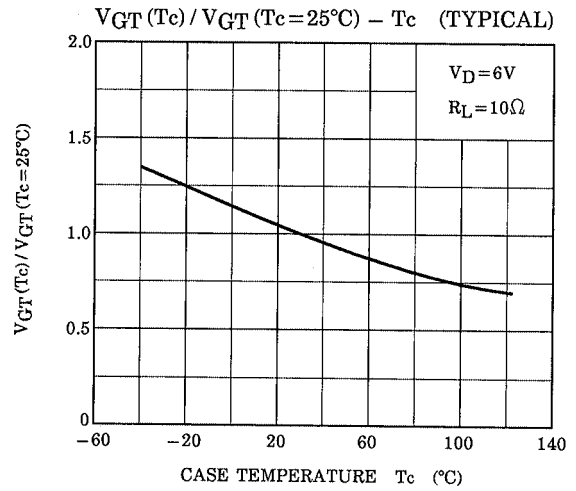
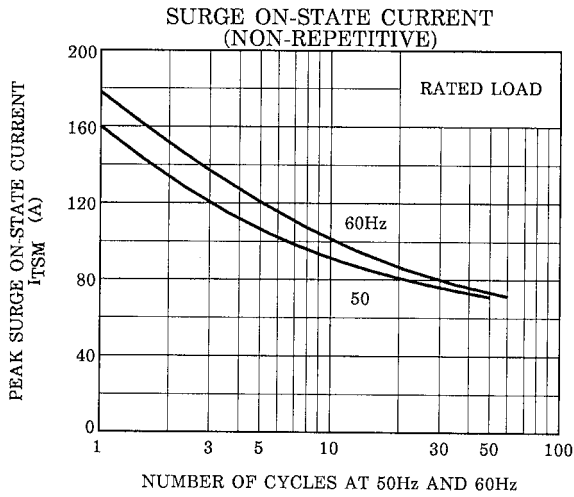
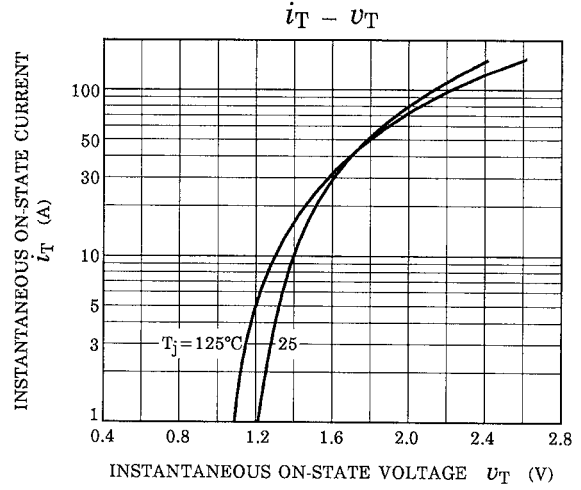
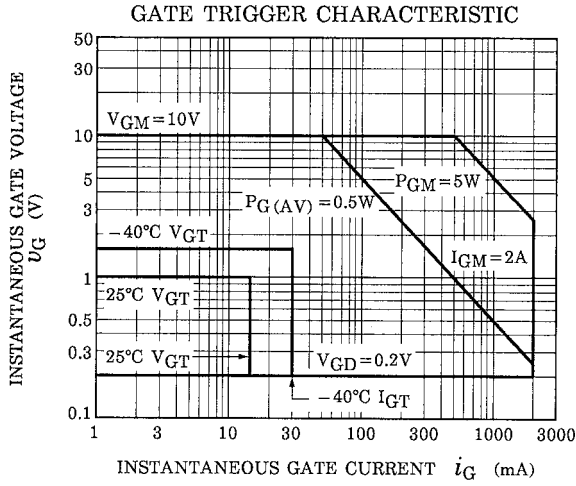
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

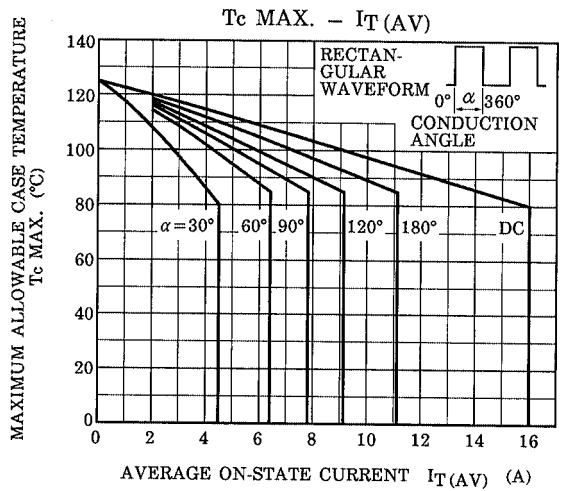
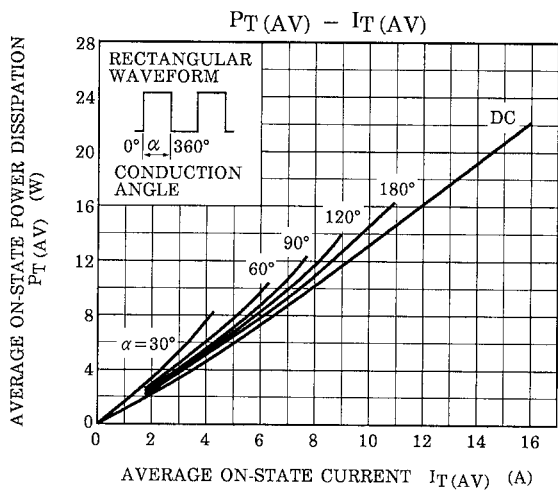
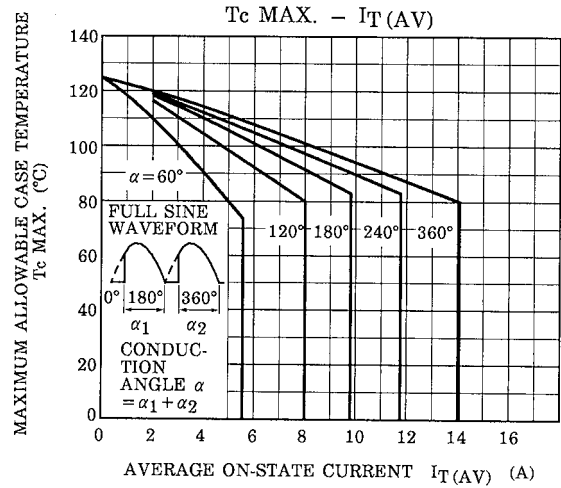
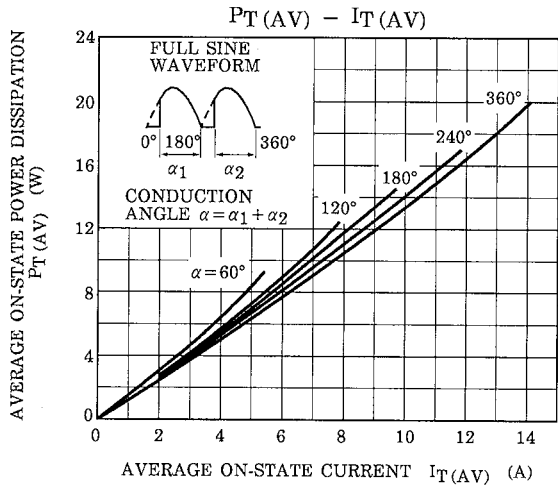
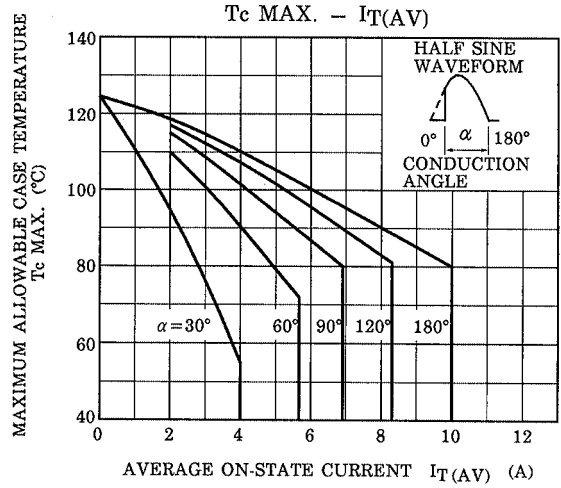
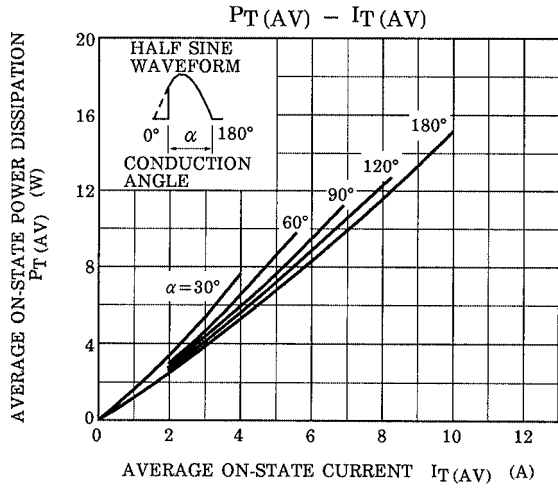
| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN | MAX | UNIT |
|---|------------------------|--|-----|-----|-----------------------------|
| Repetitive Peak Off-State Current and Repetitive Peak Reverse Current | I_{DRM} I_{RRM} | $V_{DRM} = V_{RRM} = \text{Rated}$ | — | 10 | μA |
| Peak On-State Voltage | V_{TM} | $I_{TM} = 30\text{A}$ | — | 1.6 | V |
| Gate Trigger Voltage | V_{GT} | $V_D = 6\text{V}, R_L = 10\Omega$ | — | 1.0 | V |
| Gate Trigger Current | I_{GT} | | — | 15 | mA |
| Gate Non-Trigger Voltage | V_{GD} | $V_D = \text{Rated} \times 2/3, T_c = 125^\circ\text{C}$ | 0.2 | — | V |
| Critical Rate of Rise of Off-State Voltage | dv/dt | $V_{DRM} = \text{Rated} \times 2/3, T_c = 125^\circ\text{C}$ Exponential Rise | 100 | — | V / μs |
| Holding Current | I_H | $V_D = 6\text{V}, I_{TM} = 1\text{A}$ | — | 40 | mA |
| Latching Current | I_L | $V_D = 6\text{V}, f = 50\text{Hz}, t_{gw} = 50\mu\text{s}, i_G = 30\text{mA}$ | — | 60 | mA |
| Thermal Resistance | $R_{th(j-c)}$ | Junction to Case | — | 2.0 | $^\circ\text{C} / \text{W}$ |

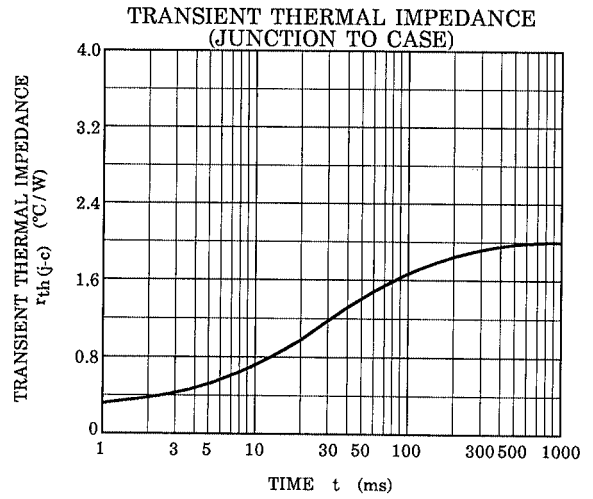
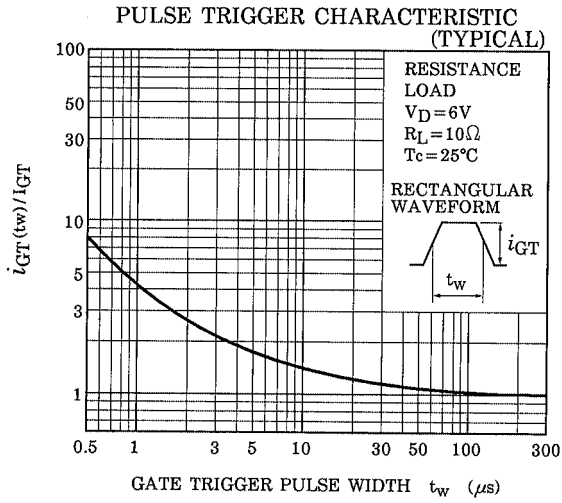
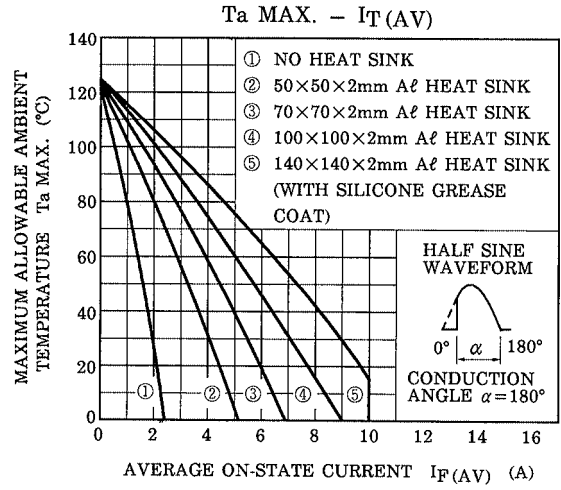
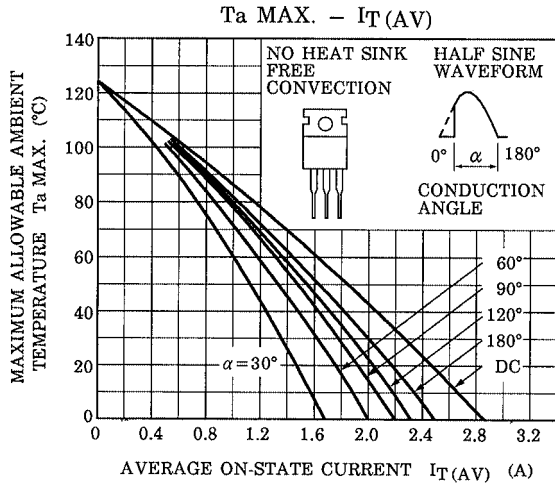
MARKING



| NUMBER | SYMBOL | MARK |
|--------|----------------------------|---|
| *1 | TYPE | SF10G41A |
| | | SF10J41A |
| *2 | SF10G41A, SF10J41A | A |
| *3 | <p>Lot Number</p> <p> </p> | <p>Example</p> <p>8A : January 1998</p> <p>8B : February 1998</p> <p>8L : December 1998</p> |







RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

Copyright Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from :

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com